

**DATA SHEET**

# SKY66185-11: 851 to 894 MHz Linear Power Amplifier

## Applications

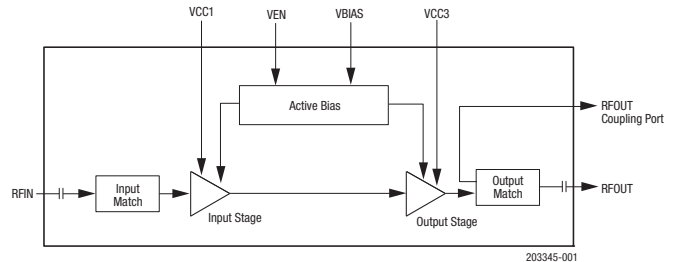
- 3G/4G LTE Bands 5, 6, 18, 19, 26, and 27 small cell
- Active distributed antenna system
- Cellular repeaters
- Driver amplifier

## Features

- High gain: 36.5 dB (unconditionally stable)
- High linearity: +23 dBm with -50 dBc ACLR @ 85°C (WCDMA Test Model 1 with 64 DPCH)
- RF input and output internally matched to 50 Ω
- Excellent output return loss: <-15 dB
- Integrated active bias: performance compensated over temp
- PA On/Off function: 6.5 μs switching time
- Integrated coupler for output power monitoring
- Single supply voltage: 3.3 V
- Minimal external components
- Pin-to-pin compatible PA family supporting all 3GPP bands
- Small 5 x 5 mm, 28-pin package (MSL3, 260 °C per JEDEC J-STD-020)



Skyworks Green™ products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green™*, document number SQ04-0074.



**Figure 1. SKY66185-11 Linear PA Block Diagram**

## Description

The SKY66185-11 is a high-linearity power amplifier (PA) with fully matched input/output and high gain. The compact 5 x 5 mm PA is designed for FDD 3G/4G LTE small cell base stations operating from 851 to 894 MHz. The active biasing circuitry is integrated to compensate PA performance over temperature, voltage, and process variation as well as an internal coupler for power monitoring.

The SKY66185-11 requires minimal external components and is part of a high-linearity, pin-to-pin compatible PA family supporting all 3GPP bands.

A block diagram of the SKY66185-11 is shown in Figure 1. The device package and pinout for the 28-pin device are shown in Figure 2. Table 1 lists the pin-to-pin compatible parts in the PA family.

**Table 1. Pin-to-Pin Compatible PA Family**

Part Number	Frequency (MHz)	LTE Band
SKY66181-11	1805 to 1880	3
SKY66184-11	2110 to 2170	1, 4, 10, and 23
SKY66185-11	851 to 894	5, 6, 18, 19, 26, and 27
SKY66186-11	728 to 768	12, 13, 14, and 17
SKY66187-11	2620 to 2690	7
SKY66188-11	758 to 803	28
SKY66189-11	1930 to 1995	2 and 25

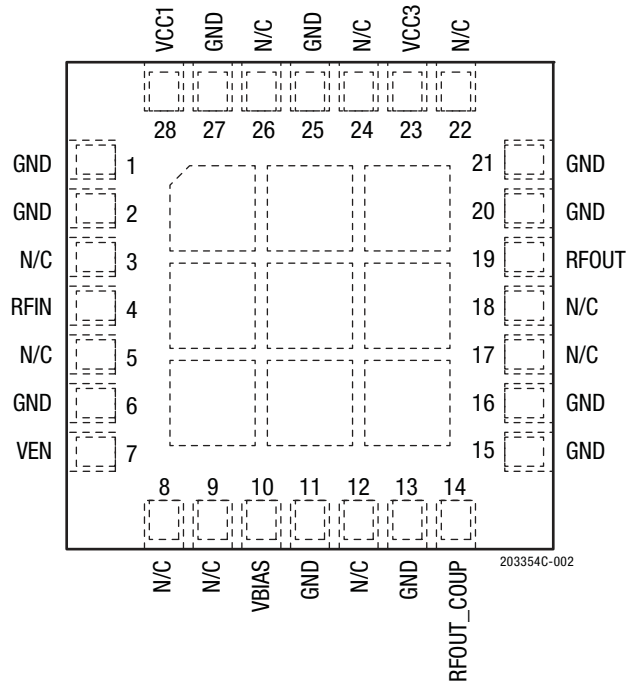


Figure 2. SKY66185-11 Pinout (Top View)

Table 2. SKY66185-11 Signal Descriptions

Pin	Name	Description	Pin	Name	Description
1	GND	Ground	15	GND	Ground
2	GND	Ground	16	GND	Ground
3	N/C	No internal connection	17	N/C	No internal connection
4	RFIN	RF input	18	N/C	No internal connection
5	N/C	No internal connection	19	RFOUT	RF output
6	GND	Ground	20	GND	Ground
7	VEN	Enable (active low)	21	GND	Ground
8	N/C	No internal connection	22	N/C	No internal connection
9	N/C	No internal connection	23	VCC3	Output stage supply voltage
10	VBIAS	Bias voltage	24	N/C	No internal connection
11	GND	Ground	25	GND	Ground
12	N/C	No internal connection	26	N/C	No internal connection
13	GND	Ground	27	GND	Ground
14	RFOUT_COUP	RF output coupling port	28	VCC1	Input stage supply voltage

## Technical Description

The SKY66185-11 PA contains all of the needed RF matching and DC biasing circuits. This two-stage device is optimized for high linearity and power efficiency. These features make the device suitable for wideband applications where PA linearity and power consumption are of critical importance (e.g., small cell and infrastructure applications).

The device is designed for standard WCDMA and LTE modulated signals. Under these stringent test conditions, the device exhibits excellent spectral purity and power efficiency.

## Electrical and Mechanical Specifications

The absolute maximum ratings of the SKY66185-11 are provided in Table 3. The recommended operating conditions are specified in Table 4, and electrical specifications are provided in Table 5.

Typical performance characteristics are shown in Figures 3 through 7.

**Table 3. SKY66185-11 Absolute Maximum Ratings<sup>1</sup>**

Parameter	Symbol	Minimum	Maximum	Units
Supply voltage (VCC)	VCC	0	+4.0	V
Total supply current	I <sub>CC</sub>		700	mA
Logic control input voltage (VEN)	VEN	-0.5	3.6	V
Case operating temperature <sup>2</sup>	T <sub>C</sub>	-40	+105	°C
Storage temperature	T <sub>STG</sub>	-55	+150	°C
Junction temperature	T <sub>J</sub>		+150	°C
Thermal resistance	θ <sub>JC</sub>		21	°C/W
Power dissipation	P <sub>DISS</sub>		2.3	W
Electrostatic discharge:	ESD			
Charged Device Model (CDM)			500	V
Human Body Model (HBM)			150	V

<sup>1</sup> Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

<sup>2</sup> Case operating temperature (T<sub>C</sub>) refers to the temperature of the bottom ground pad.

**ESD HANDLING:** Although this device is designed to be as robust as possible, electrostatic discharge (ESD) can damage this device. This device must be protected at all times from ESD when handling or transporting. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD handling precautions should be used at all times.

**Table 4. SKY66185-11 Recommended Operating Conditions**

Parameter	Symbol	Minimum	Typical	Maximum	Units
Frequency range	f	851		894	MHz
Supply voltage (VCC1, VCC2, VCC3) <sup>1</sup>	VCC	3.0	3.3	3.6	V
PA enable control voltage (active low):					
Disable	VENH	2.5		3.6	V
Enable	VENL	0		0.6	V
PA enable current (@ PAEN = 3.6 V)	I <sub>EN</sub>			<1	mA
Case operating temperature	T <sub>C</sub>	+25	+40	+85	°C

<sup>1</sup> Voltage levels measured at the pads of the package. The Evaluation Board supply voltage levels may be different.

**Table 5. SKY66185-11 Electrical Specifications<sup>1</sup>**

**(V<sub>CC</sub> = +3.3 V, T<sub>c</sub> = +25 °C, f = 872.5 MHz, Characteristic Impedance [Z<sub>0</sub>] = 50 Ω, V<sub>EN</sub> = 0 V, Unless Otherwise Noted)**

Parameter	Symbol	Test Condition	Min	Typical	Max	Units
Gain	G@23dBm	CW, P <sub>OUT</sub> = +23 dBm:				
		851 MHz	36.0	36.5		dB
		872.5 MHz	36.0	36.3		dB
		894 MHz	35.5	36.0		dB
Input return loss	IS11I	CW, P <sub>IN</sub> = -30 dBm	8.0	10.0		dB
Output return loss:	IS22I	CW, P <sub>IN</sub> = -30 dBm:				
			In-band frequency: 851 and 894 MHz	11.0	15.0	
Out-of-band		Out-of-band frequency: 831 and 914 MHz	10.0	13.0		dB
Quiescent current	I <sub>Q</sub>	No RF		130	160	mA
Operating current	I <sub>CC</sub>	CW, P <sub>OUT</sub> = +23 dBm		420	480	mA
Power-down current	I <sub>PD</sub>	V <sub>EN</sub> = 2.5 V		0.1	1.5	mA
Adjacent channel leakage ratio	ACLR	@ 5 MHz offset, WCDMA test model 1, with 64 DPCH, 8.5 dB PAR, P <sub>OUT</sub> = +23 dBm		-50	-46.5	dBc
Output 1 dB compression point	OP1dB	CW (Gain compression less than 1dB reference to G@23dBm)	+30.3	+30.8		dBm
Power-added efficiency	PAE	CW @ P <sub>OUT</sub> = +23 dBm	12	14		%
Output coupling factor	C <sub>PL</sub> OUT	P <sub>OUT</sub> = +23 dBm, CW	16	18	20	dB

<sup>1</sup> Performance is guaranteed only under the conditions listed in this table.

### Typical Performance Characteristics

(V<sub>CC</sub> = +3.3 V, T<sub>c</sub> = +25 °C, f = 872.5 MHz, Characteristic Impedance [Z<sub>0</sub>] = 50 Ω, V<sub>EN</sub> = 0 V, Unless Otherwise Noted)

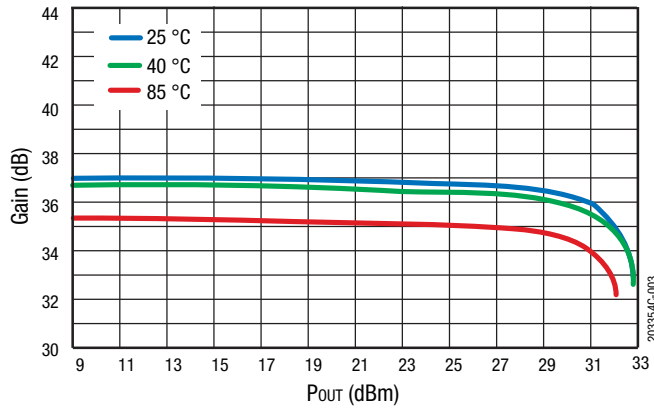


Figure 3. Gain vs Output Power

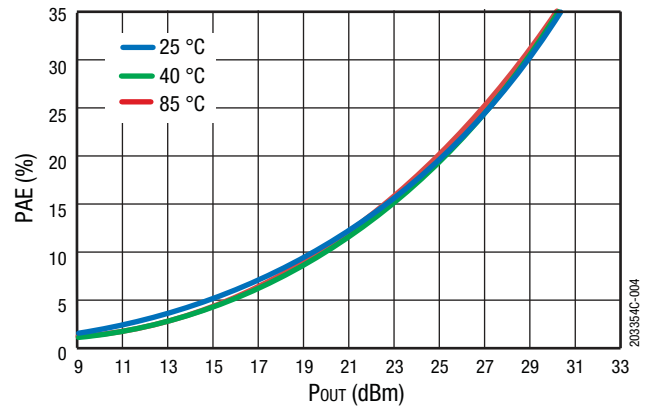


Figure 4. PAE vs Output Power

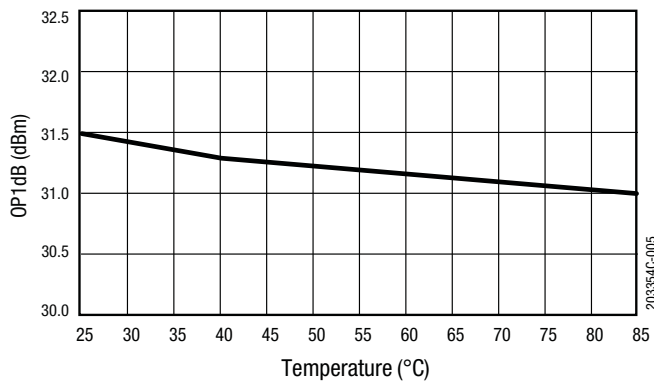


Figure 5. OP1dB vs Temperature

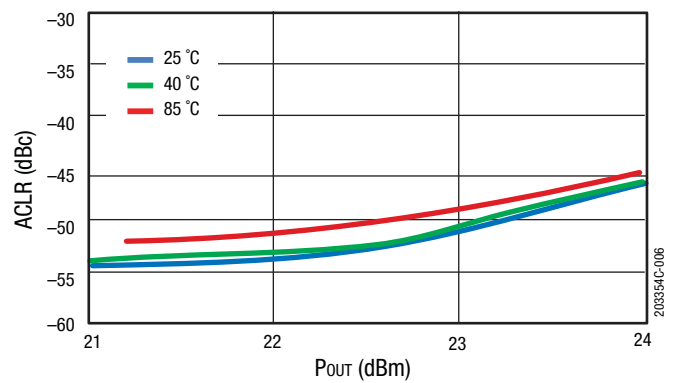


Figure 6. ACLR vs Output Power

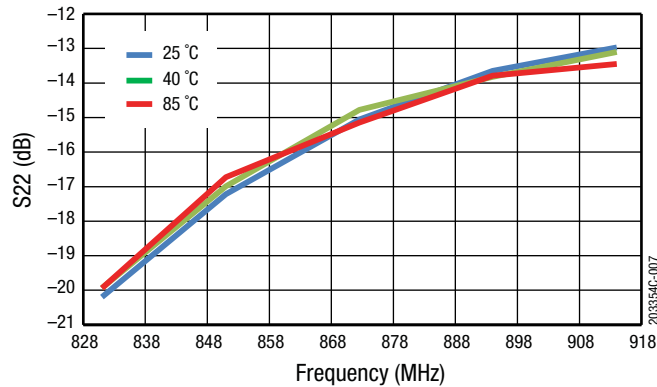


Figure 7. S<sub>22</sub> vs Frequency across Temperature

## Evaluation Board Description

The SKY66185-11 Evaluation Board is used to test the performance of the SKY66185-11 PA. A typical application schematic diagram is shown in Figure 8. A Bill of Materials for the SKY66185-11 Evaluation Board is listed in Table 6. An assembly drawing for the Evaluation Board is shown in Figure 9. The board layer detail is shown in Figure 10. The layer detail physical characteristics are shown in Figure 11.

## Application Circuit Notes

**Center Ground.** It is extremely important to sufficiently ground the bottom ground pad of the device for both thermal and stability reasons. Multiple small vias are acceptable and work well under the device if solder migration is an issue.

**GND (pins 1, 2, 6, 11, 13, 15, 16, 20, 21, 25, and 27).** Attach all ground pins to the RF ground plane with the largest diameter and lowest inductance via that the layout allows. Multiple small vias are acceptable and work well under the device if solder migration is an issue.

**VBIAS (pin 10).** The bias supply voltage for each stage, nominally set to +3.3 V.

**RFOUT (pin 19).** Amplifier RF output pin ( $Z_0 = 50 \Omega$ ). The module includes an onboard internal DC blocking capacitor. All impedance matching is provided internal to the module.

**VCC1 and VCC3 (pins 28 and 23, respectively).** Supply voltage for each stage collector bias is nominally set to 3.3 V. Bypass and decoupling capacitors C1, C2, C5, and C6 should be placed in the approximate location shown on the evaluation board assembly drawing, although exact placement is not critical.

**RFIN (pin 4).** Amplifier RF input pin ( $Z_0 = 50 \Omega$ ). The module includes an onboard internal DC blocking capacitor. All impedance matching is provided internal to the module.

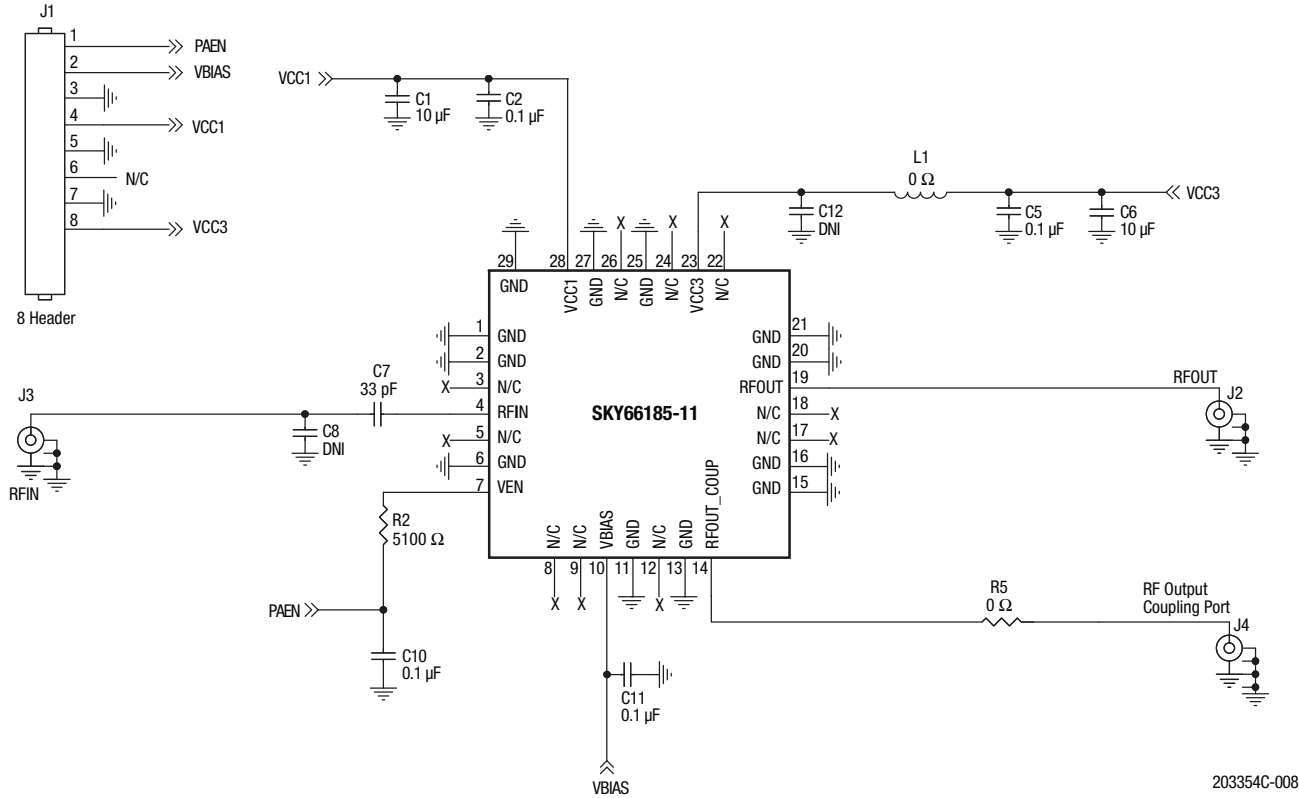
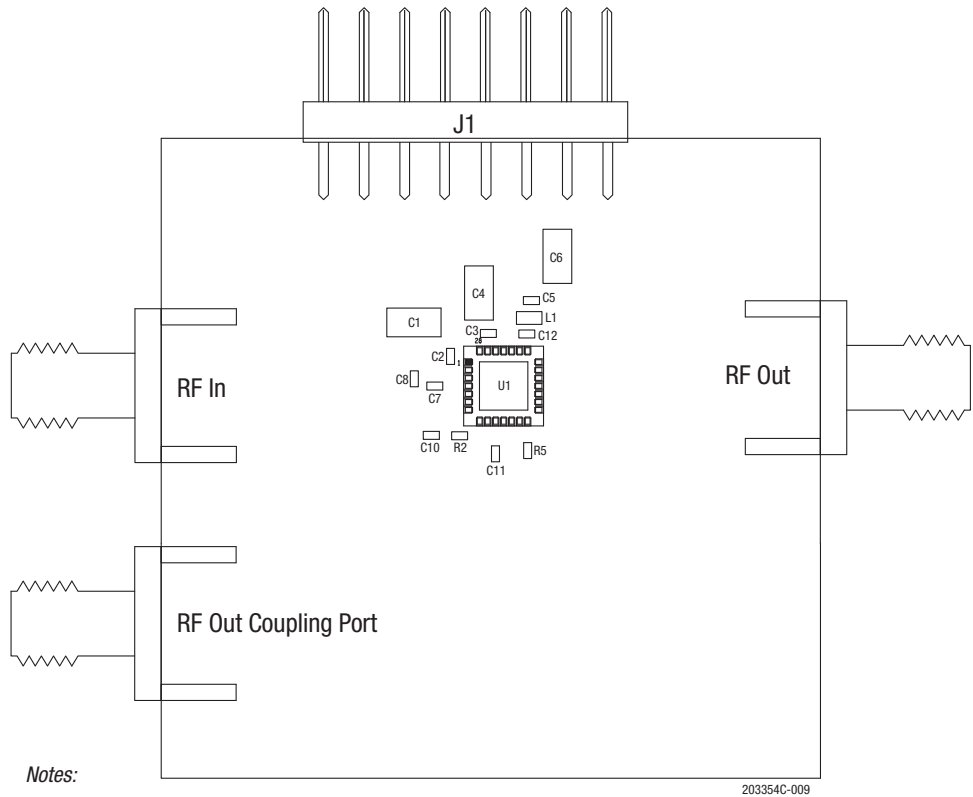


Figure 8. SKY66185-11 Application Schematic

Table 6. SKY66185-11 Evaluation Board Bill of Materials (BOM)

Quantity	Component	Size	Part Number	Description
2	C1, C6	1206	C1206X7R160-106KNE	Capacitor, 10 $\mu$ F, 16 V, $\pm$ 10%, X7R
3	C2, C5, C10, C11	0402	GRM155R71C104KA88	Ceramic capacitor, 0.1 $\mu$ F, 10%, X7R, 16 V
1	C7	0402	GRM1555C1H330JZ01	Capacitor, 33 pF, 50 V, $\pm$ 5%, X7R
3	C8, C12		DNI	DNI
1	L1	0603	RM73ZIJ000	Resistor, 0 $\Omega$ , 5%
1	R5	0402	ERJ2GE0R00	Resistor, 0 $\Omega$ , jumper, 0.063 W
1		PCB	TW22-D115-002	SKY66185
1	R2	0402	ERJ2GEJ512	Resistor, 5100 $\Omega$ , 5%, 0.063 W



Notes:

The C3 and C4 components are not required.  
Some of the other components shown are optional.

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**Figure 9. SKY66185-10 Evaluation Board Assembly Diagram**



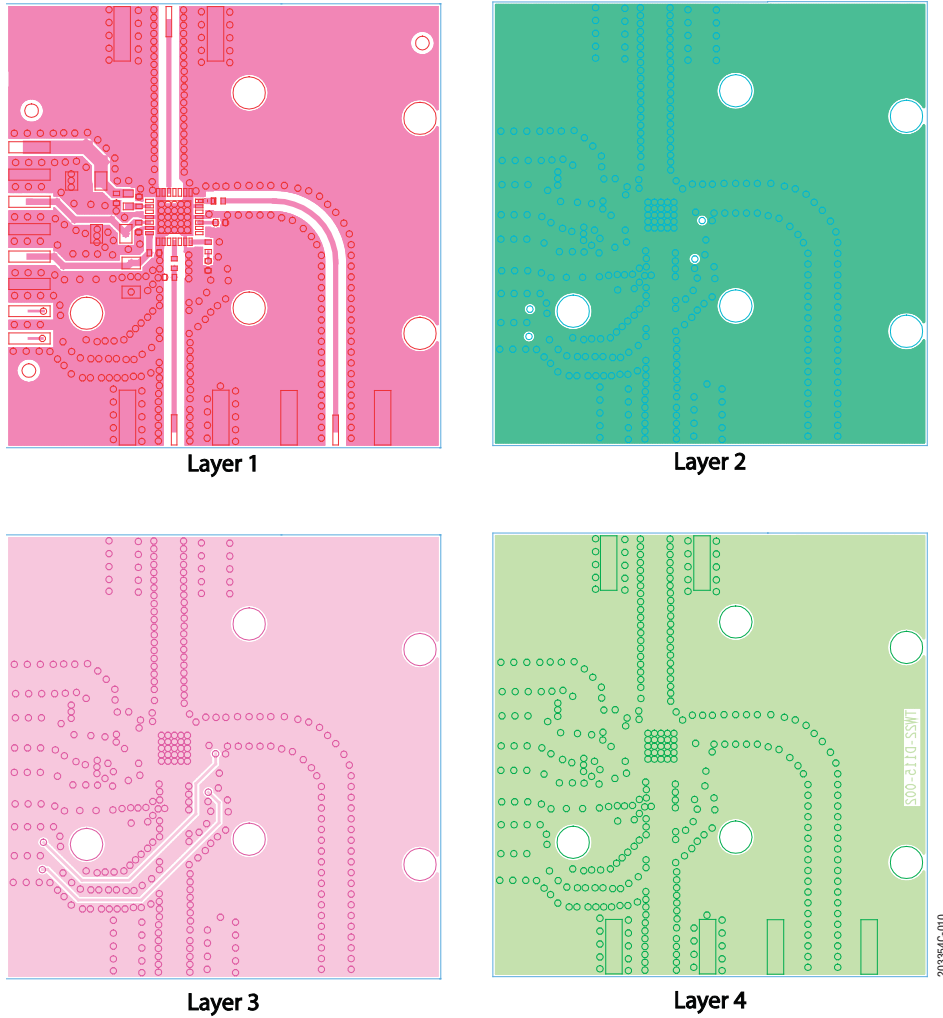


Figure 10. SKY66185-11 Board Layer Detail

Cross Section	Name	Thickness (mm)	Material
	Top Solder Mask	0.010	Solder Resist
	L1	0.035	Cu – 1 oz
	Dielectric	0.250	Rogers R04350B
	L2	0.035	Cu – 1 oz
	Dielectric	0.500	FR4
	L3	0.035	Cu – 1 oz
	Dielectric	0.250	FR4
	L4	0.035	Cu – 1 oz
	Bottom Solder Mask	0.010	Solder Resist

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Figure 11. SKY66185-11 Layer Detail Physical Characteristics

### Package Dimensions

The typical part marking is shown in Figure 12. Figure 13 shows the PCB layout footprint. Figure 14 shows the package dimensions, and Figure 15 provides the tape and reel dimensions.

### Package and Handling Information

Since the device package is sensitive to moisture absorption, it is baked and vacuum packed before shipping. Instructions on the shipping container label regarding exposure to moisture after the container seal is broken must be followed. Otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly.

The SKY66185-11 is rated to Moisture Sensitivity Level 3 (MSL3) at 260 °C. It can be used for lead or lead-free soldering. For additional information, refer to the Skyworks Application Note, *PCB Design and SMT Assembly/Rework Guidelines for MCM-L Packages*, document number 101752.

Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. Production quantities of this product are shipped in a standard tape and reel format.

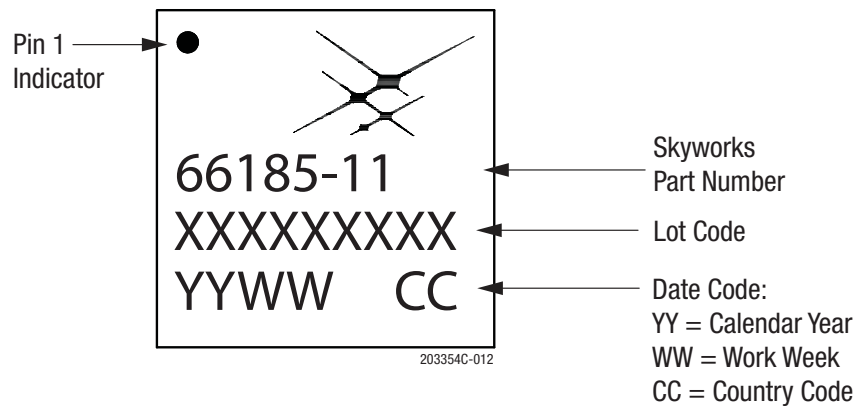
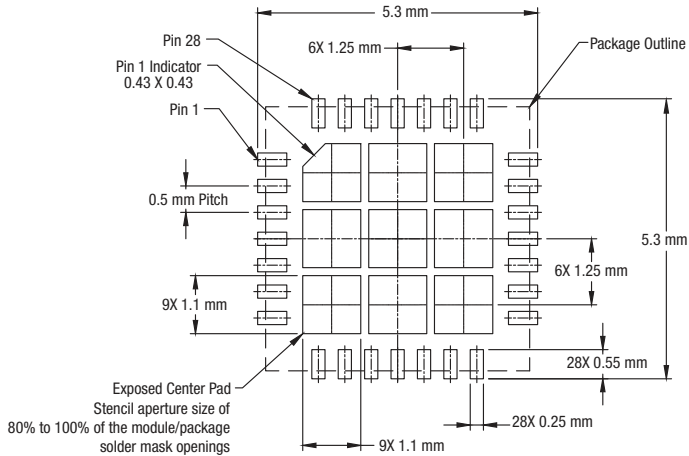
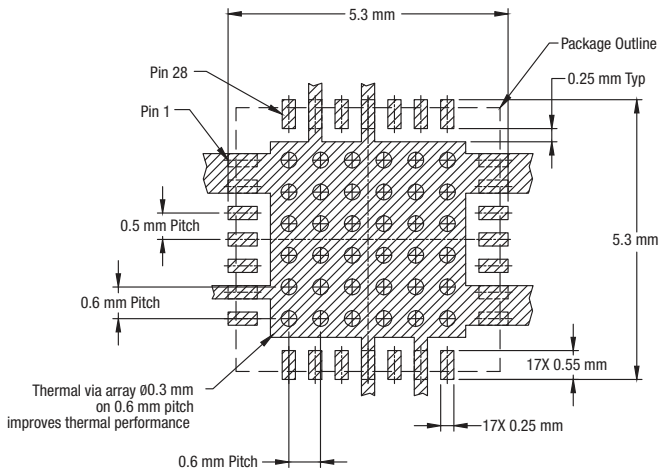


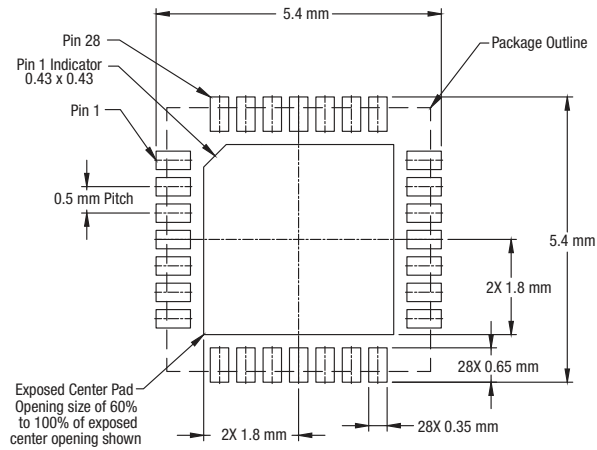
Figure 12. Typical Part Marking



Stencil Aperture Top View



Metallization Top View



Solder Mask Opening Top View

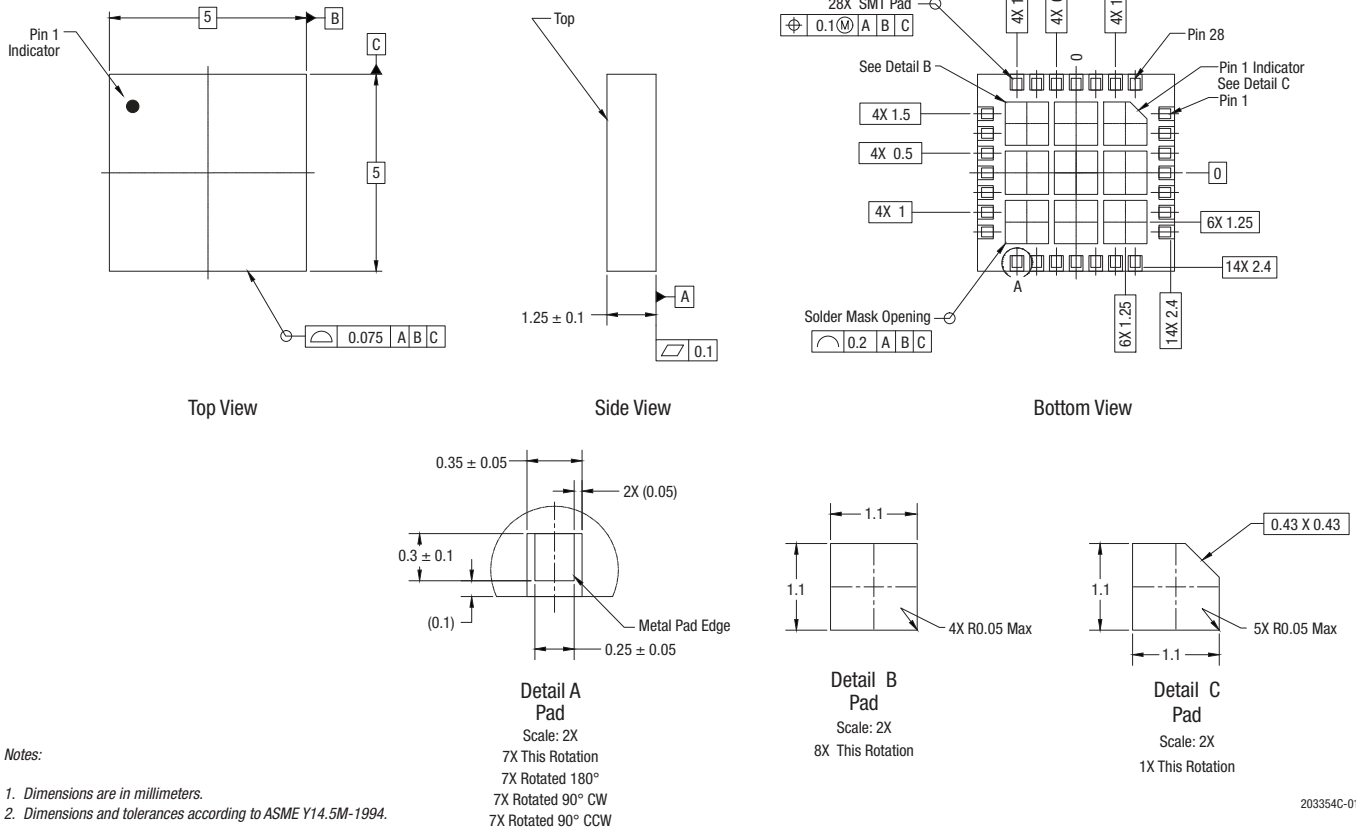
Notes:

1. Thermal vias should be resin filled and capped in accordance with IPC-4761 type VII vias.
2. Recommended Cu thickness is 30 to 35  $\mu\text{m}$ .

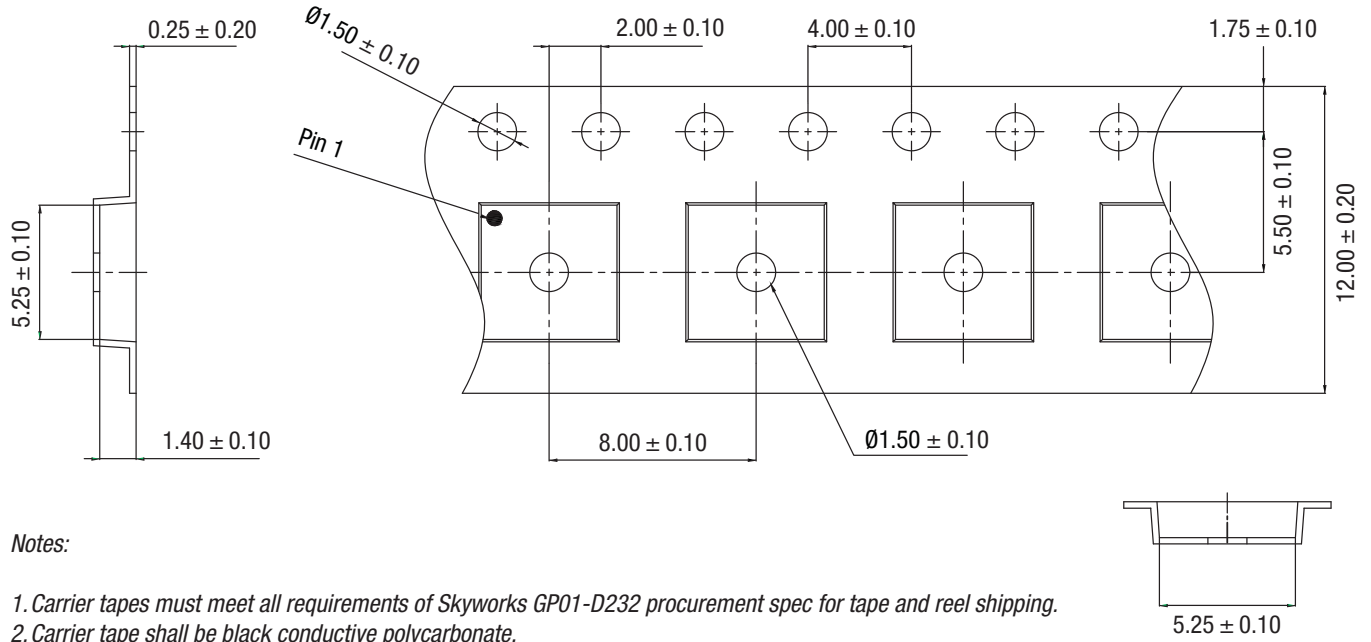
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Figure 13. SKY66185-11 PCB Layout Footprint

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**Figure 14. SKY66185-11 Package Dimensions**



Notes:

1. Carrier tapes must meet all requirements of Skyworks GP01-D232 procurement spec for tape and reel shipping.
2. Carrier tape shall be black conductive polycarbonate.
3. Cover tape shall be transparent conductive material.
4. ESD-surface resistivity shall be  $\leq 1 \times 10^{10} \Omega/\text{square}$  per EJA, JEDEC TNR specification.
5. All measurements are in millimeters.

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**Figure 15. SKY66185-11 Tape and Reel Dimensions**